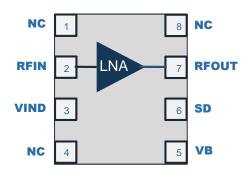


Low Noise, High Linearity Amplifier 400MHz to 1500MHz

RFMD's RFLA1022 is a Low Noise, High Linearity Amplifier housed in a 2.0mm x 2.0mm DFN package. The LNA features a shutdown (SD) pin that can be used to turn off the LNA. The V_{BIAS} (VB) pin can be used to adjust the current of the LNA. Noise figure of 0.45dB and an IIP3 of 27dBm make this component ideal for receiver input lineups. This module is internally matched to 50 Ω on all RF ports but does require DC blocks and bias feed inductors.



Functional Block Diagram

Ordering Information

RFLA1022SQ	Sample bag with 25 pieces
RFLA1022SR	7" Reel with 100 pieces
RFLA1022TR7	7" Reel with 2500 pieces
RFLA1022PCK-410	400MHz to 1500MHz PCBA with 5-piece sample bag



Package: DFN, 8-pin, 2.0mm x 2.0mm

Features

- Frequency Range 400MHz to 1500MHz
- Matched Internally, DC Blocks Required
- Shutdown Mode
- Gain = 17.5dB at 880MHz
- Noise Figure of 0.45dB Typical
- Input IP3 = 27dBm
- Single +3V / +5V Supply
- Small 8-Pin, 2.0mm x 2.0mm DFN

Applications

- LTE, TD-LTE, 3G, and 2G Cellular Infrastructure Application
- PA Driver Amplifiers
- Low Noise, High Linearity Gain Blocks

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Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage	+5.5	V _{DC}
Control Voltage	+5.5	V _{DC}
DC Supply Current	230	mA
Power Dissipation	1.25	W
Max RF Input Power	32	dBm
Storage Temperature	-40 to +150	°C
ESD Rating (HBM)	250	V
Moisture Sensitivity Level	MSL1	





RFMD Green: RoHS status based on EU Directive 2011/65/EU (at time of this document revision), halogen free per IEC 61249-2-21, < 1000pm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

Recommended Operating Condition

Parameter	S	on	Unit	
	Min	Тур	Max	Onit
Operating Temperature Range	-40		+85	°C
Operating Junction Temperature			150	°C
Supply Voltage		5 ¹		V
Supply vollage		3 ²		V

Notes

1. 5V Operation

2. 3V Operation

Nominal Operating Parameters

Deremeter	S	pecificat	ion	Unit	Condition
Parameter	Min	Тур	Max	Unit	Condition
LNA Performance					Temp = 25°C, V _{CC} = 5V, 140mA, 880MHz, Standard Application Circuit
Frequency Range	400		1500	MHz	
Gain (On Mode)		17.5		dB	SD = 5V
Noise Figure		0.45		dB	
Input P1dB		5.5		dBm	
Input IP3		27		dBm	
Gain (Off Mode)		10		dB	SD = 0V
Input Return Loss		-16		dB	
Output Return Loss		-15		dB	SD = 5V
LNA Performance					Temp = 25°C, V _{CC} = 3V, 80mA, 880MHz, Standard Application Circuit
Frequency Range	400		1500	MHz	

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Parameter	S	pecificat	ion	Unit	Condition
Falameter	Min	Тур	Мах	Unit	Condition
LNA Performance - Continued					Temp = 25°C, V _{CC} = 3V, 80mA, 880MHz, Standard Application Circuit
Gain (On Mode)		16.5		dB	SD = 3V
Noise Figure		0.39		dB	
Input P1dB		2.5		dBm	
Input IP3		17		dBm	
Gain (Off Mode)		0		dB	SD = 0V
Input Return Loss		-14.5		dB	SD = 3V
Output Return Loss		-17		dB	30 = 3V
Overall					
SD Voltage	0		VCC	V	
Logic High			VCC	V	5V Operation
Logic Low	0			V	
SD Voltage	0		VCC	V	
Logic High			VCC	V	3V Operation
Logic Low	0			V	
Thermal Resistance		51		°C/W	85°C at 120mA, 5V
Current					
		140		mA	On Mode, SD =5V, 5V operation
Current		1		mA	Off Mode, SD = 0V, 5V operation
Guilent		80		mA	On Mode, SD = 3V, 3V operation
		1		mA	Off mode, SD = 0V, 3V operation

Typical RF Performance: 5V, 800MHz 25°C

Parameter	Unit	1.1V	1.4V	2.0V	2.6V	3.2V	3.8V	4.2V	4.5V
Gain	dB	16.42	16.6	16.9	17	17.1	17.2	17.2	17.2
Noise Figure	dB	0.34	0.34	0.35	0.35	0.37	0.40	0.43	0.44
Input IP3	dBm	16.12	14	17.7	21.5	24	28.1	29	27.5
Input P1dB	dBm	-3.2	-1.42	0.96	2.8	4.2	5.4	5.87	6.22
Input Return Loss	dB	-14	-14.5	-15.2	-15.5	-15.6	-15.8	-15.8	-15.9
Output Return Loss	dB	-13	-14	-14.4	-14.8	-15	-15.1	-15.2	-15.2
VCC Current	mA	32	43	65	85	106	126	140	150
SD Current	mA	0.238	0.24	0.23	0.28	0.22	0.22	0.22	0.23
VB Current	mA	0.63	0.89	1.43	1.97	2.5	3.06	3.42	3.68

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Typical RF Performance: 3V, 800MHz, 25°C

Parameter	Unit	1.3V	1.6V	1.9V	2.2V	2.85V	3.0V
Gain	dB	16.1	16.3	16.4	16.6	16.7	16.8
Noise Figure	dB	0.36	0.34	0.34	0.35	0.36	0.36
Input IP3	dBm	13.92	13.3	14.2	15.2	15.9	16
Input P1dB	dBm	-2.7	-1.21	0	0.8	2.1	2.2
Input Return Loss	dB	-13	-13.5	-13.8	-14	-14.4	-14.5
Output Return Loss	dB	-14.9	-15.6	-16.1	-16.4	-16.8	-16.9
VCC Current	mA	32	42	52	62	82	88
SD Current	mA	0.11	0.11	0.1	0.1	0.1	0.1
VB Current	mA	0.79	1.06	1.32	1.58	2.2	2.3

Typical RF Performance: 5V, 25°C, VB = 1.1V

Parameter	Unit	400MHz	600MHz	800MHz	1000MHz	1200MHz	1500MHz
Gain	dB	22.47	19.37	17.17	15.33	13.76	11.77
Noise Figure	dB	0.28	0.36	0.34	0.42	0.46	0.55
Input IP3	dBm	10.91	13.45	16.12	15.58	15.36	15.73
Input P1dB	dBm	-4.59	-3.47	-3.16	-3.27	-3.2	-3.33
Input Return Loss	dB	-12.8	-13.26	-13.87	-14.38	-14.82	-14.91
Output Return Loss	dB	-17.12	-15.55	-13.68	-12.12	-10.85	-9.43
VCC Current	mA	32	32	32	32	32	32
SD Current	mA	0.23	0.34	0.24	0.23	0.23	0.23
VB Current	mA	0.61	0.61	0.63	0.62	0.63	0.62

Typical RF Performance: 5V, 25°C, VB = 1.4V

Parameter	Unit	400MHz	600MHz	800MHz	1000MHz	1200MHz	1500MHz
Gain	dB	22.72	19.58	17.4	15.54	13.97	11.99
Noise Figure	dB	0.26	0.34	0.34	0.41	0.45	0.55
Input IP3	dBm	10.47	12.1	14	15.47	16.84	18.96
Input P1dB	dBm	-3.15	-1.77	-1.42	-1.64	-1.63	-1.71
Input Return Loss	dB	-13.78	-13.93	-14.42	-14.94	-15.34	-15.31
Output Return Loss	dB	-18.94	-16.71	-14.42	-12.66	-11.28	-9.75
VCC Current	mA	43	43	43	43	43	43
SD Current	mA	0.23	0.35	0.23	0.24	0.23	0.23
VB Current	mA	0.88	0.88	0.89	0.89	0.89	0.89

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Typical RF Performance: 5V, 25°C, VB = 2.0V

Parameter	Unit	400MHz	600MHz	800MHz	1000MHz	1200MHz	1500MHz
Gain	dB	23	19.84	17.63	15.77	14.21	12.25
Noise Figure	dB	0.27	0.34	0.35	0.43	0.47	0.59
Input IP3	dBm	13.77	15.43	17.71	20.21	21.96	21.18
Input P1dB	dBm	-0.69	0.75	0.96	0.91	0.98	0.66
Input Return Loss	dB	-14.94	-14.64	-15.03	-15.53	-15.91	-15.67
Output Return Loss	dB	-20.91	-18.09	-15.27	-13.26	-11.71	-10.13
VCC Current	mA	65	65	65	65	65	65
SD Current	mA	0.22	0.37	0.23	0.23	0.23	0.23
VB Current	mA	1.41	1.41	1.43	1.42	1.42	1.41

Typical RF Performance: 5V, 25°C, VB = 2.6V

Parameter	Unit	400MHz	600MHz	800MHz	1000MHz	1200MHz	1500MHz
Gain	dB	23.14	19.96	17.77	15.92	14.35	12.4
Noise Figure	dB	0.27	0.35	0.35	0.44	0.48	0.62
Input IP3	dBm	17.13	19.4	21.5	22.31	21.35	19.41
Input P1dB	dBm	0.8	2.65	2.79	2.77	2.57	2.57
Input Return Loss	dB	-15.59	-15.05	-15.35	-15.8	-16.14	-15.82
Output Return Loss	dB	-21.75	-18.89	-15.69	-13.55	-11.95	-10.32
VCC Current	mA	85	85	85	85	85	85
SD Current	mA	0.22	0.37	0.23	0.24	0.23	0.23
VB Current	mA	1.95	1.96	1.97	1.96	1.96	1.96

Typical RF Performance: 5V, 25°C, VB = 3.2V

Parameter	Unit	400MHz	600MHz	800MHz	1000MHz	1200MHz	1500MHz
Gain	dB	23.23	20.04	17.85	15.99	14.44	12.5
Noise Figure	dB	0.28	0.35	0.37	0.47	0.5	0.66
Input IP3	dBm	19.34	21.37	23.98	22.84	21.05	19.09
Input P1dB	dBm	1.42	3.64	4.2	4.3	4.19	4.07
Input Return Loss	dB	-16.01	-15.3	-15.54	-15.98	-16.29	-15.86
Output Return Loss	dB	-22.09	-19.33	-15.94	-13.72	-12.06	-10.43
VCC Current	mA	106	106	106	106	106	106
SD Current	mA	0.22	0.37	0.22	0.23	0.22	0.23
VB Current	mA	2.5	2.5	2.51	2.5	2.51	2.5

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Typical RF Performance: 5V, 25°C, VB = 3.8V

Parameter	Unit	400MHz	600MHz	800MHz	1000MHz	1200MHz	1500MHz
Gain	dB	23.69	20.1	17.91	16.05	14.53	12.57
Noise Figure	dB	0.3	0.37	0.4	0.48	0.57	0.69
Input IP3	dBm	19.63	20.34	28.06	23.74	22.6	19.78
Input P1dB	dBm	1.73	4.11	5.35	5.5	6.15	5.13
Input Return Loss	dB	-16.32	-15.44	-15.68	-16.09	-16.4	-15.87
Output Return Loss	dB	-22.16	-19.63	-16.1	-13.81	-12.17	-10.5
VCC Current	mA	126	126	126	126	126	126
SD Current	mA	0.22	0.38	0.22	0.22	0.22	0.22
VB Current	mA	3.05	3.06	3.06	3.05	3.41	3.05

Typical RF Performance: 5V, 25°C, VB = 4.2V

Parameter	Unit	400MHz	600MHz	800MHz	1000MHz	1200MHz	1500MHz
Gain	dB	23.31	20.12	17.94	16.08	14.53	12.59
Noise Figure	dB	0.32	0.4	0.43	0.51	0.57	0.73
Input IP3	dBm	19.06	19.27	29.04	24.85	22.6	20.53
Input P1dB	dBm	1.9	4.32	5.87	6.29	6.15	6
Input Return Loss	dB	-16.46	-15.53	-15.72	-16.15	-16.40	-15.88
Output Return Loss	dB	-22.13	-19.71	-16.14	-13.83	-12.17	-10.53
VCC Current	mA	140	140	140	140	140	140
SD Current	mA	0.22	0.38	0.22	0.22	0.22	0.22
VB Current	mA	3.41	3.41	3.42	3.41	3.41	3.41

Typical RF Performance: 5V, 25°C, VB = 4.5V

Parameter	Unit	400MHz	600MHz	800MHz	1000MHz	1200MHz	1500MHz
Gain	dB	23.32	20.14	17.94	16.09	14.54	12.62
Noise Figure	dB	0.34	0.42	0.44	0.54	0.59	0.75
Input IP3	dBm	18.46	18.57	27.54	25.71	23.56	21.21
Input P1dB	dBm	2	4.48	6.22	6.81	6.68	6.6
Input Return Loss	dB	-16.58	-15.59	-15.77	-16.14	-16.4	-15.87
Output Return Loss	dB	-22.14	-19.82	-16.18	-13.85	-12.16	-10.52
VCC Current	mA	150	150	150	150	150	150
SD Current	mA	0.22	0.38	0.22	0.21	0.22	0.22
VB Current	mA	3.67	3.68	3.69	3.68	3.68	3.68

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Typical RF Performance: 3V, 25°C, VB = 1.3V

Parameter	Unit	400MHz	600MHz	800MHz	1000MHz	1200MHz	1500MHz
Gain	dB	22.17	19.01	16.81	14.98	13.44	11.51
Noise Figure	dB	0.28	0.35	0.36	0.42	0.46	0.55
Input IP3	dBm	9.25	11.24	13.92	14.78	15.39	16.71
Input P1dB	dBm	-4.91	-3.05	-2.69	-2.63	-2.57	-2.66
Input Return Loss	dB	-12.01	-12.34	-12.86	-13.39	-13.89	-14.19
Output Return Loss	dB	-20.78	-17.48	-15.61	-13.98	-12.65	-11.24
VCC Current	mA	32	32	32	32	32	32
SD Current	mA	0.1	0.21	0.11	0.11	0.1	0.11
VB Current	mA	0.78	0.78	0.79	0.79	0.79	0.8

Typical RF Performance: 3V, 25°C, VB = 1.6V

Parameter	Unit	400MHz	600MHz	800MHz	1000MHz	1200MHz	1500MHz
Gain	dB	22.42	19.24	17.03	15.19	13.65	11.73
Noise Figure	dB	0.27	0.34	0.34	0.41	0.46	0.56
Input IP3	dBm	9.17	10.85	13.27	15.34	17.11	19.8
Input P1dB	dBm	-3.69	-1.77	-1.21	-1.16	-1.09	-1.27
Input Return Loss	dB	-12.79	-12.88	-13.32	-13.87	-14.37	-14.61
Output Return Loss	dB	-24.18	-18.82	-16.48	-14.58	-13.11	-11.6
VCC Current	mA	42	42	42	42	42	42
SD Current	mA	0.1	0.22	0.1	0.1	0.1	0.1
VB Current	mA	1.04	1.05	1.06	1.06	1.06	1.06

Typical RF Performance: 3V, 25°C, VB = 1.9V

Parameter	Unit	400MHz	600MHz	800MHz	1000MHz	1200MHz	1500MHz
Gain	dB	22.58	19.39	17.19	15.34	13.8	11.88
Noise Figure	dB	0.27	0.34	0.34	0.43	0.45	0.57
Input IP3	dBm	9.74	11.52	14.22	16.82	18.89	20.82
Input P1dB	dBm	-2.86	-0.85	-0.04	-0.07	0.01	-0.07
Input Return Loss	dB	-13.33	-13.22	-13.62	-14.17	-14.69	-14.87
Output Return Loss	dB	-27.15	-19.74	-17	-14.96	-13.4	-11.85
VCC Current	mA	52	52	52	52	52	52
SD Current	mA	0.11	0.22	0.1	0.1	0.1	0.1
VB Current	mA	1.3	1.31	1.32	1.32	1.32	1.33

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Typical RF Performance: 3V, 25°C, VB = 2.2V

Parameter	Unit	400MHz	600MHz	800MHz	1000MHz	1200MHz	1500MHz
Gain	dB	22.71	19.5	17.3	15.47	13.91	12.19
Noise Figure	dB	0.25	0.34	0.35	0.42	0.47	0.62
Input IP3	dBm	10.14	12.1	15.14	17.84	19.7	18.86
Input P1dB	dBm	-2.49	-0.25	0.8	0.91	0.98	2.63
Input Return Loss	dB	-13.76	-13.51	-13.88	-14.39	-14.92	-15.27
Output Return Loss	dB	-30.55	-20.49	-17.41	-15.19	-13.57	-12.15
VCC Current	mA	62	62	62	62	62	62
SD Current	mA	0.11	0.23	0.1	0.1	0.1	0.1
VB Current	mA	1.57	1.58	1.58	1.58	1.58	2.17

Typical RF Performance: 3V, 25°C, VB = 2.85V

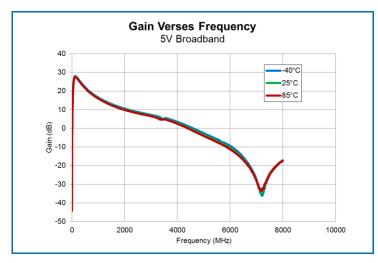
Parameter	Unit	400MHz	600MHz	800MHz	1000MHz	1200MHz	1500MHz
Gain	dB	22.88	19.71	17.47	15.64	14.1	12.19
Noise Figure	dB	0.26	0.35	0.36	0.44	0.5	0.62
Input IP3	dBm	9.92	11.97	15.89	18.65	19.6	18.86
Input P1dB	dBm	-2.12	0.43	2.06	2.42	2.67	2.63
Input Return Loss	dB	-14.42	-14.02	-14.27	-14.79	-15.27	-15.27
Output Return Loss	dB	-36.47	-21.73	-17.93	-15.48	-13.77	-12.15
VCC Current	mA	82	82	82	82	82	82
SD Current	mA	0.1	0.24	0.1	0.1	0.09	0.1
VB Current	mA	2.16	2.31	2.16	2.17	2.17	2.17

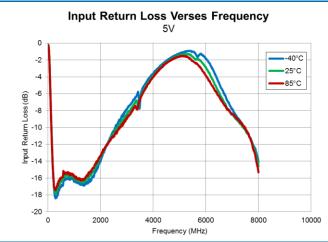
Typical RF Performance: 3V, 25°C, VB = 3.0V

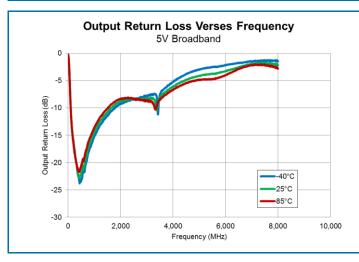
Parameter	Unit	400MHz	600MHz	800MHz	1000MHz	1200MHz	1500MHz
Gain	dB	22.92	19.71	17.52	15.65	14.13	12.23
Noise Figure	dB	0.27	0.35	0.36	0.44	0.48	0.63
Input IP3	dBm	9.79	11.97	15.95	18.81	19.62	18.87
Input P1dB	dBm	-2.07	0.43	2.24	2.85	3.04	3.08
Input Return Loss	dB	-14.54	-14.02	-14.3	-14.88	-15.35	-15.32
Output Return Loss	dB	-36.48	-21.73	-18.03	-15.52	-13.8	-12.16
VCC Current	mA	88	88	88	88	88	88
SD Current	mA	0.1	0.24	0.1	0.09	0.1	0.1
VB Current	mA	2.29	2.31	2.3	2.3	2.31	2.31

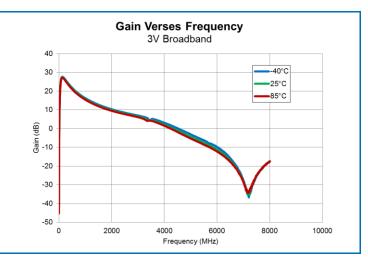
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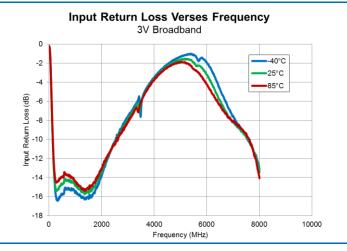


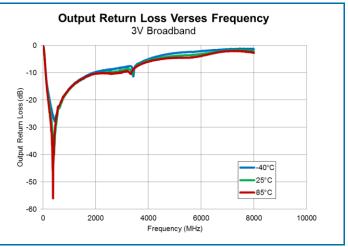










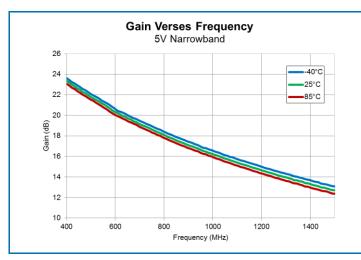


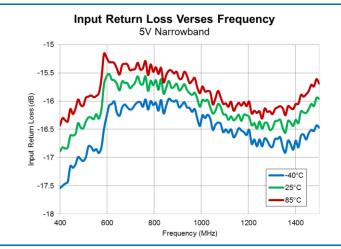
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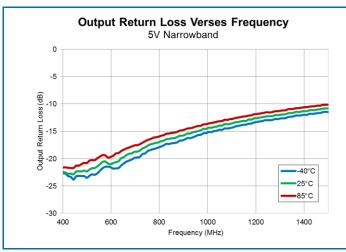
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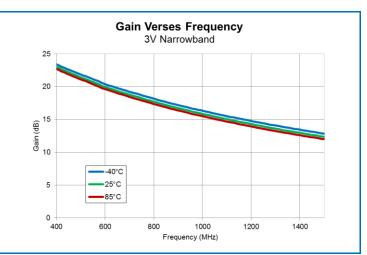




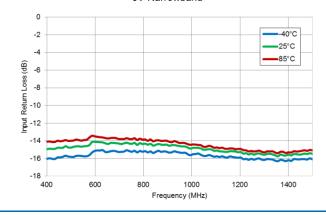








Input Return Loss Verses Frequency 3V Narrowband

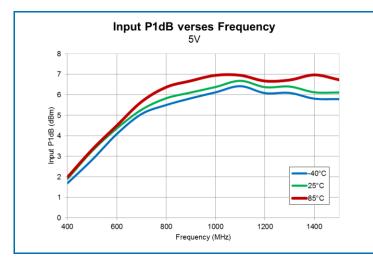


Output Return Loss Verses Frequency 3V Narrowband 0 -5 -10 (gp -15 Loss -20 Return I -25 Output -30 -40°C -35 25°C -40 85°C -45 400 600 1.200 1.400 800 1.000 Frequency (MHz)

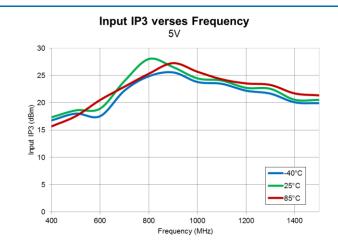
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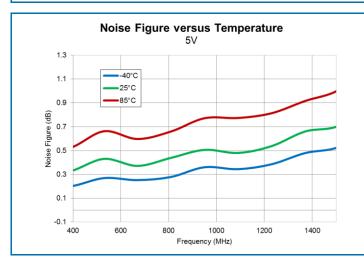
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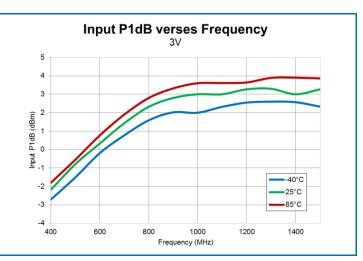


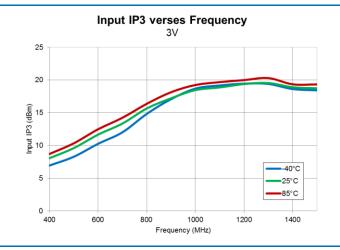


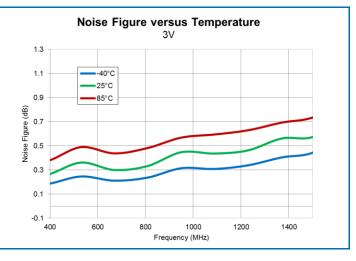
Typical Performance: $V_{DD} = 5V$, Current = 140mA and $V_{DD} = 3V$, Current 80mA







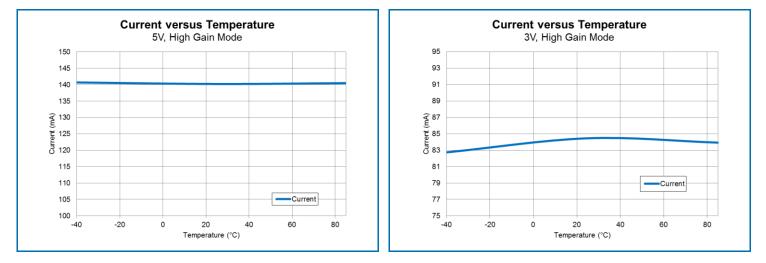




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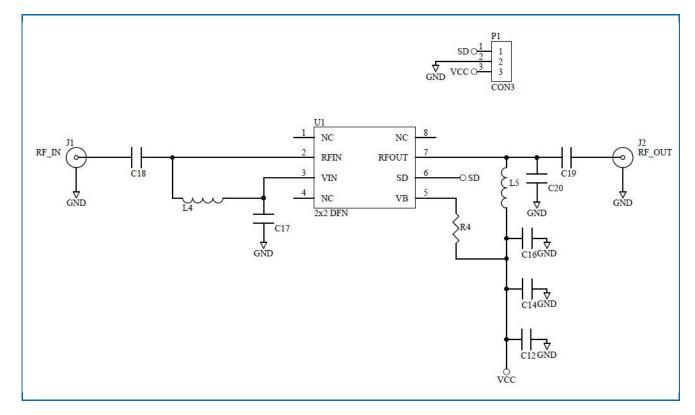


Typical Performance: $V_{DD} = 5V$, Current = 140mA and $V_{DD} = 3V$, Current 80mA





Evaluation Board Schematic Wideband Tune



Evaluation Board Bill of Materials (BOM)

Description	Reference Designator	Manufacturer	Manufacturer's P/N
Evaluation Board		DDI	LA1022-410(B)
RFLA1022 Module	U1	RFMD	RFLA1022
CAP, 0.1µF, 10%, 16v, X7R, 0402	C14, C17	Murata Electronics	GRM155R71C104KA88D
CAP, 10pF, 5%, 50V, C0G, 0402	C16	Murata Electronics	GRM1555C1H100JA01D
CAP, 22µF, 10%, 10V, TANT-A	C4	AVX Corporation	TAJA226K010RNJ
CAP, 10000pF, 10%, 50V, X7R, 0603	C18-C19	Murata Electronics	GRM188R71H103KA01D
CONN, SMA, END LNCH, UNIV, HYB MNT, FLT	J1, J6	Heilind Electronics	PER MAT-21-1022
CAP, 1.0pF, ±0.25pF, 50V, COG, 0402	C20	Murata Electronics	GRM1555C1HR0CA01D
RES, 0Ω, 0402	R4	Kamaya, inc.	RMC1/16SJPTH
CONN, HDR, ST, PLRZD, 4-PIN	P1	ITW Pancon	MPSS100-4C
IND, 82nH, 5%, W/W, 0603	L4-L5	Coilcraft, inc.	0603CS-82NXJLW

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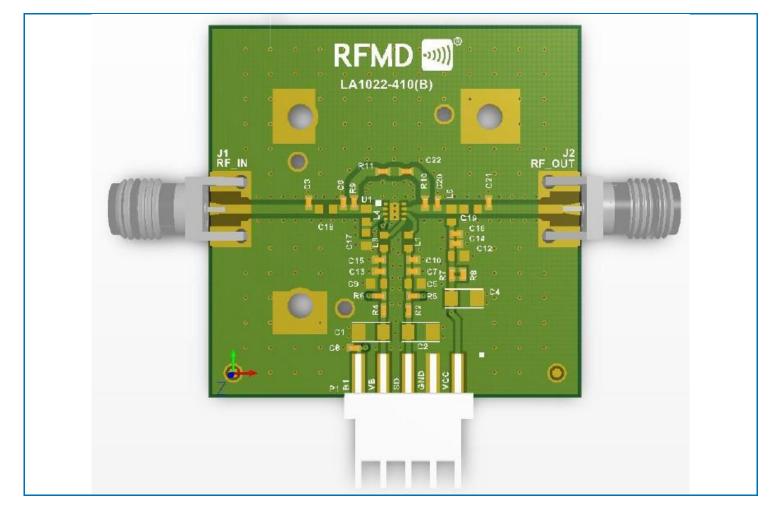
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Evaluation Board Assembly Drawing





Pin Names and Descriptions

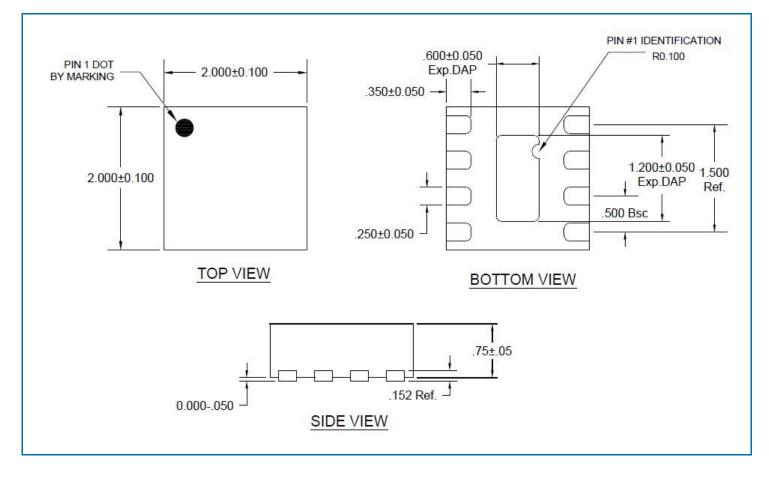
Pin	Name	Description	
1	NC	No connect	
2	RFIN	RF Input; Internally 50Ω matched, DC block required	
3	VIND	xternal gate bias fed through a choke inductor to pin 2	
4	NC	No connect	
5	VB	Bias voltage	
6	SD	Shutdown pin to turn off the LNA	
7	RFOUT	RF Output; Internally 50Ω matched, DC block required	
8	NC	No connect	

Truth Table

	SD
LNA On	1
LNA Off	0

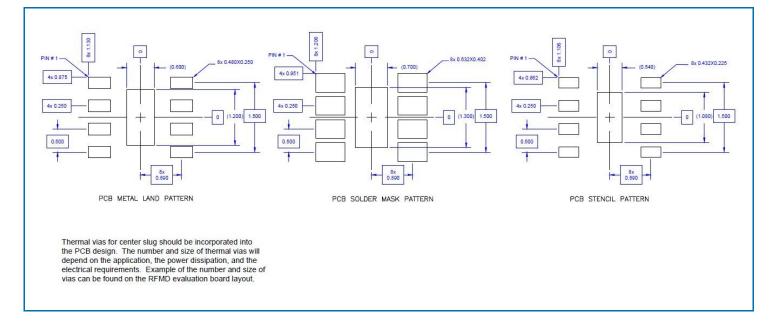


Package Outline Drawing (Dimensions in millimeters)





Stencil, PCB Pattern



Branding Diagram

